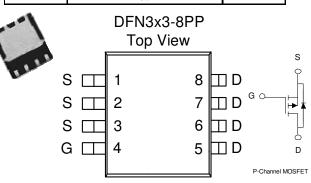
P-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, cellular and cordless telephones.

•	Low r _{DS(on)} provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
-40	19 @ $V_{GS} = -10V$	-12			
-40	27 @ V _{GS} = -4.5V	-10			



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			-40	V		
Gate-Source Voltage	V_{GS}	±20	V			
	$T_A=25^{\circ}C$] T_	-12			
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-10	A		
Pulsed Drain Current ^b	I_{DM}	±50				
Continuous Source Current (Diode Conduction) ^a		I_S	-2.1	A		
D. D a	$T_A=25^{\circ}C$	D	3.5	w		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	rD	2.0	VV		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Maximum	Units			
a	t <= 10 sec	ъ	35	°C/W			
Maximum Junction-to-Ambient ^a	Steady State	$ R_{0JA} $	81	°C/W			

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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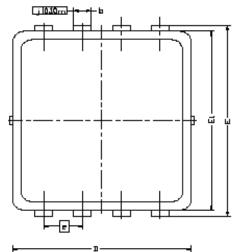
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Conditions	Limits			Unit		
i didiletei	Cyrribor	rest conditions		Тур	Max			
Static								
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \text{ uA}$	-1			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current	1	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$	_{OS} = -32 V, V _{GS} = 0 V		-1			
Zero date Voltage Brain Guirent	I _{DSS}	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5	uA		
On-State Drain Current ^A	I _{D(on)}	V_{DS} = -5 V, V_{GS} = -10 V	-50			Α		
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$			19	mΩ		
Diam-Source On-Hesistance		$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$			27	11152		
Forward Tranconductance ^A	9 _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -1 \text{ A}$		29		S		
Diode Forward Voltage	V_{SD}	$I_S = 1 A$, $V_{GS} = 0 V$		-0.8		V		
Dynamic ^b								
Total Gate Charge	Q_g	$V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V},$		10				
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V},$ $I_{D} = -1 \text{ A}$		4		nC		
Gate-Drain Charge	Q_{gd}	ID = -1 M		6				
Turn-On Delay Time	t _{d(on)}			10				
Rise Time	t _r	$V_{DD} =$ -15 V, $R_L = 6 \; \Omega$,		10		nS		
Turn-Off Delay Time	t _{d(off)}	$I_D = -1 A$, $V_{GEN} = -10 V$		100				
Fall-Time	t _f			50				

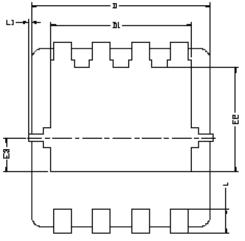
Notes

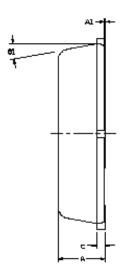
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







DIM.	MIL	LIMETE	:RS	INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0,700	0'80	0.900	0.0276	0.0315	0.0354
A1	0.00		0.05	0.000		0.002
b	0.24	0.30	0.35	0.009	0.012	0.014
C	0.10	0.152	0.25	0,004	0,006	0.010
D	3.00 BSC 0.118 BSC				C	
D1	2.35 B2C			0.093 BSC		
Ε	3,20 BSC			0,	126 BS	S.
E1	3.00 BSC			٥	.118 BS	C.
E5	1.75 BSC			a.	069 BS	C 2
E3	0.575 BSC			0.	023 BS	3C
6	0.65 BSC			Ō.	026 BS	C 2
L	0,30	0,40	0,50	0,0118	0.0157	0.0197
L1			0.100	D		0.004
9 1	٥٥	10*	12*	٥٠	10*	12*